

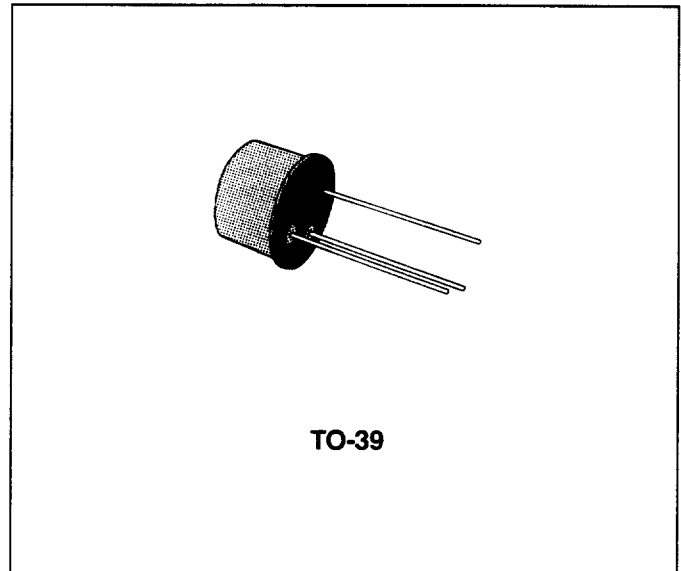


**MEDIUM POWER AMPLIFIER**

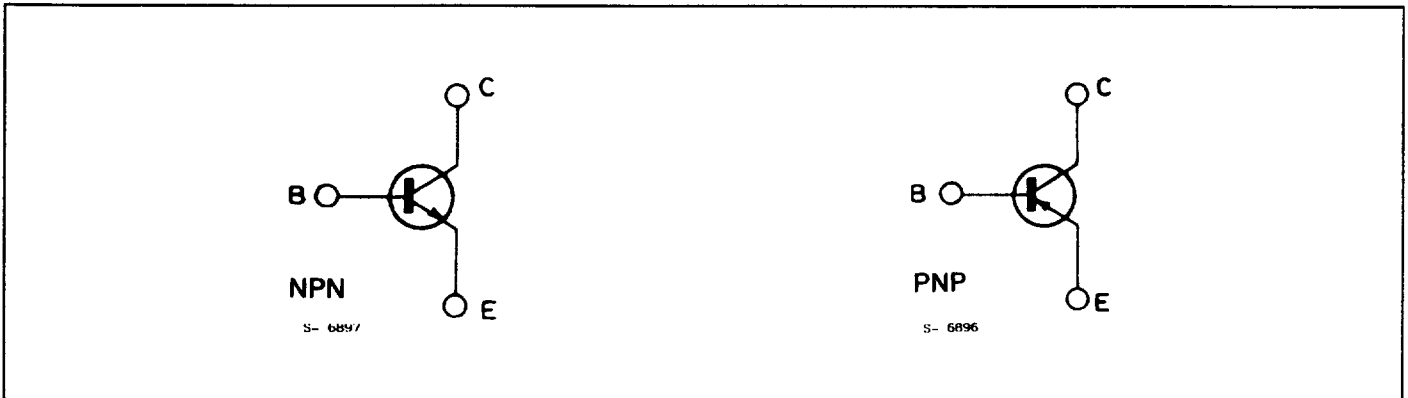
**DESCRIPTION**

The BC440 and BC441 are silicon planar epitaxial NPN transistors in TO-39 metal case. They are intended for general purpose applications, especially for driver stages.

The complementary PNP types are respectively the BC460 and BC461.



**INTERNAL SCHEMATIC DIAGRAM**



**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value		Unit
		BC440	BC441	
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	50	70	V
$V_{CEO(sus)}$	Collector-emitter Voltage ( $I_B = 0$ )	40	60	V
$V_{CER}$	Collector-emitter Voltage ( $R_{BE} \leq 100 \Omega$ )	50	70	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	5		V
$I_{CM}$	Collector Peak Current	2		A
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25^\circ C$ at $T_{case} \leq 25^\circ C$	1		W
		10		W
$T_{stg}$	Storage Temperature	- 65 to 200		$^\circ C$
$T_j$	Junction Temperature	200		$^\circ C$

# BC440-BC441

## THERMAL DATA

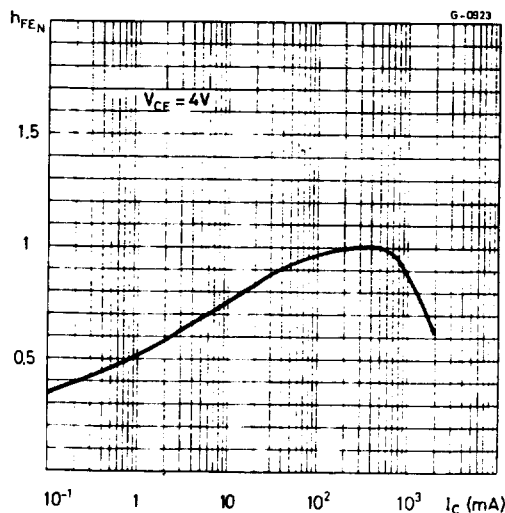
$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	17.5	°C/W
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max	175	°C/W

## ELECTRICAL CHARACTERISTICS ( $T_{case} = 25\ ^\circ C$ unless otherwise specified)

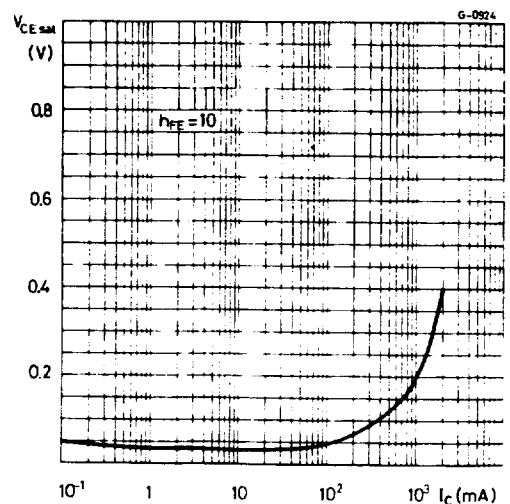
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector Cutoff Current ( $I_E = 0$ )	$V_{CB} = 40\ V$			100	nA
$I_{CER}$	Collector Cutoff Current ( $R_{BE} = 100\ \Omega$ )	For <b>BC440</b> $V_{CE} = 50\ V$ For <b>BC441</b> $V_{CE} = 70\ V$			10 10	$\mu A$ $\mu A$
$V_{(BR)\ EBO}$	Emitter Base Breakdown Voltage ( $I_C = 0$ )	$I_E = 100\ \mu A$	5			V
$V_{(BR)\ CEO}^*$	Collector-emitter Breakdown Voltage ( $I_B = 0$ )	$I_C = 10\ mA$ For <b>BC440</b> For <b>BC441</b>	40 60			V V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 1\ A$ $I_B = 100\ mA$			1	V
$V_{BE(sat)}$	Base-emitter Saturation Voltage	$I_C = 1\ A$ $I_B = 100\ mA$			1.5	V
$h_{FE}^*$	DC Current Gain	Gr. 4 $I_C = 500\ mA$ $V_{CE} = 4\ V$ Gr. 5 $I_C = 500\ mA$ $V_{CE} = 4\ V$ Gr. 6 $I_C = 500\ mA$ $V_{CE} = 4\ V$ $I_C = 1\ A$ $V_{CE} = 2\ V$ (for <b>BC440</b> only)	40 60 115 20		70 130 250	
$f_T$	Transition frequency	$I_C = 50\ mA$ $V_{CE} = 4\ V$	50			MHz

\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle = 1 %.

DC Normalized Current Gain.

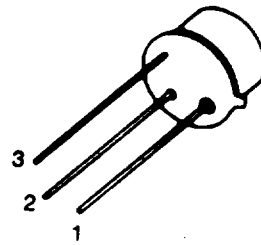


Collector-emitter Saturation Voltage.

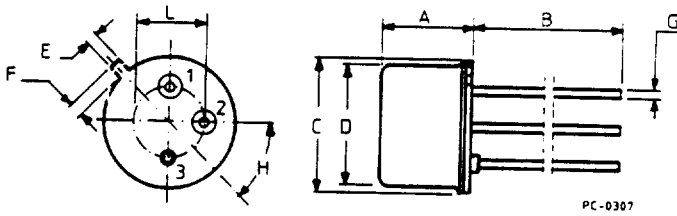


# PACKAGES

## TO-39



### MECHANICAL DATA



	DIMENSIONS			
	mm		inches	
	min	max	min	max
A	—	6.6	—	0.260
B	12.7	—	0.500	—
C	—	9.4	—	0.370
D	—	8.5	—	0.334
E	—	0.9	—	0.035
F	—	1.2	—	0.047
G	—	0.49	—	0.019
H	45° typ		45° typ	
L	5.08 typ		0.200 typ	

pin 1: Emitter - pin 2: Base - pin 3: Collector